N-Channel Silicon MOSFET

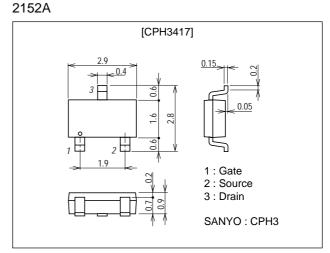


## Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 1.8V drive.

## **Package Dimensions**

unit : mm



# **Specifications**

### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	۱D		1.8	A
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	7.2	А
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm <sup>2</sup> X0.8mm)	0.9	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +125	°C

#### Electrical Characteristics at Ta=25°C

Symbol	Conditions	Ratings			Unit
		min	typ	max	Unit
V(BR)DSS	ID=1mA, VGS=0	20			V
IDSS	VDS=20V, VGS=0			1	μA
IGSS	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0			±10	μΑ
VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	0.4		1.3	V
yfs	VDS=10V, ID=1A	1.9	2.8		S
R <sub>DS</sub> (on)1	ID=1A, VGS=4V		160	210	mΩ
R <sub>DS</sub> (on)2	ID=0.5A, VGS=2.5V		200	280	mΩ
RDS(on)3	ID=0.1A, VGS=1.8V		280	390	mΩ
	V(BR)DSS IDSS IGSS VGS(off)  yfs  RDS(on)1 RDS(on)2	V(BR)DSS ID=1mA, VGS=0   IDSS VDS=20V, VGS=0   IGSS VGS=16V, VDS=0   VGS(off) VDS=10V, ID=1mA    yfs  VDS=10V, ID=1A   RDS(on)1 ID=1A, VGS=4V   RDS(on)2 ID=0.5A, VGS=2.5V	V(BR)DSS ID=1mA, VGS=0 20   IDSS VDS=20V, VGS=0 20   IGSS VGS=48V, VDS=0 20   VGS(off) VDS=10V, ID=1mA 0.4    yfs  VDS=10V, ID=1A 1.9   RDS(on)1 ID=1A, VGS=4V 20   RDS(on)2 ID=0.5A, VGS=2.5V 20	Symbol Conditions min typ   V(BR)DSS ID=1mA, VGS=0 20 20   IDSS VDS=20V, VGS=0 20 20   IGSS VGS=±8V, VDS=0 20 20   VGS(off) VDS=10V, ID=1mA 0.4 20    yfs  VDS=10V, ID=1A 1.9 2.8   RDS(on)1 ID=1A, VGS=4V 160 200   RDS(on)2 ID=0.5A, VGS=2.5V 200 200	Symbol Conditions min typ max   V(BR)DSS ID=1mA, VGS=0 20 1   IDSS VDS=20V, VGS=0 1 1   IGSS VGS=±8V, VDS=0 1 ±10   VGS(off) VDS=10V, ID=1mA 0.4 1.3    yfs  VDS=10V, ID=1A, VGS=4V 1.9 2.8   RDS(on)1 ID=1A, VGS=4V 160 210   RDS(on)2 ID=0.5A, VGS=2.5V 200 280

Marking : KS

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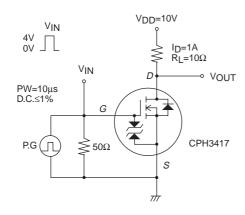
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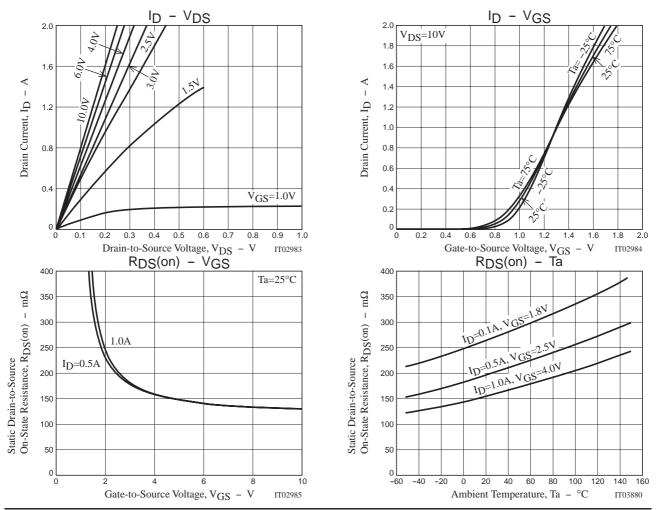
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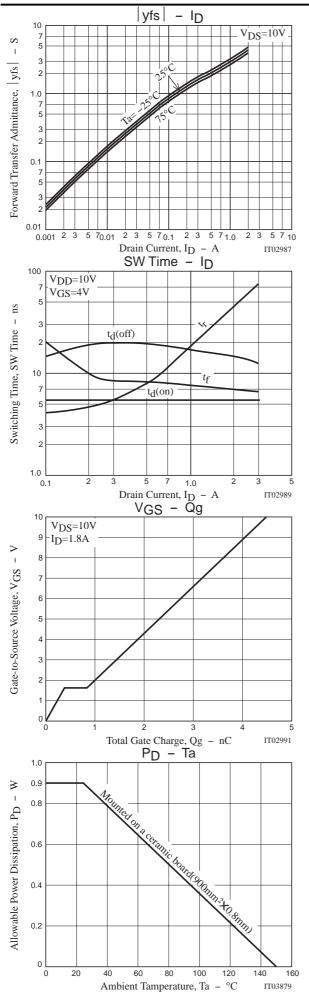
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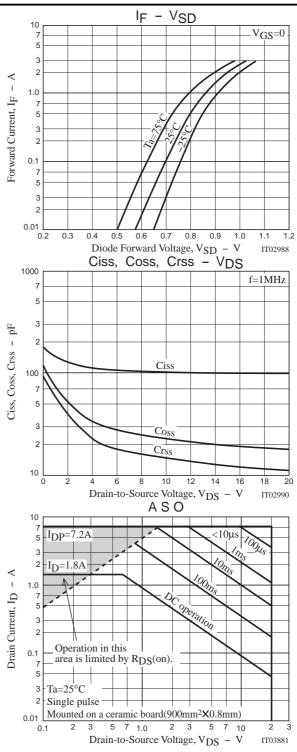
Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss	V <sub>DS</sub> =10V, f=1MHz		100		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		22		pF
Reverse Transfer Capacitance	Crss	VDS=10V, f=1MHz		15		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		5.5		ns
Rise Time	tr	See specified Test Circuit.		18		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		17		ns
Fall Time	tf	See specified Test Circuit.		8		ns
Total Gate Charge	Qg	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =1.8A		4.5		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =1.8A		0.4		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =1.8A		0.4		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1.8A, V <sub>GS</sub> =0		0.91	1.2	V

## Switching Time Test Circuit









Note on usage : Since the CPH3417 is designed for high-speed switching applications, please avoid using this device in the vicinity of highly charged objects.

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